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# MC1490

# RF/IF/Audio Amplifier

The MC1490 is an integrated circuit featuring wide–range AGC for use in RF/IF amplifiers and audio amplifiers over the temperature range,  $-40^{\circ}$  to +85°C.

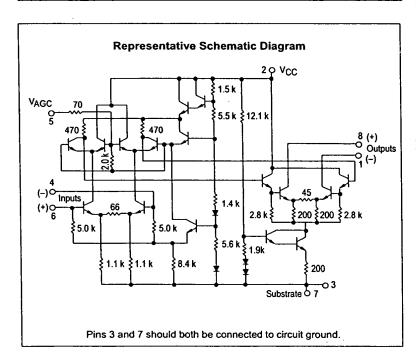
- High Power Gain: 50 dB Typ at 10 MHz
   45 dB Typ at 60 MHz
   35 dB Typ at 100 MHz
- Wide Range AGC: 60 dB Min, DC to 60 MHz
- 6.0 V to 15 V Operation, Single Polarity Supply
- See MC1350D for Surface Mount

# MAXIMUM RATINGS (T<sub>A</sub> = +25°C, unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Supply Voltage	Vcc	+18	Vdc
AGC Supply	VAGC	Vcc	Vdc
Input Differential Voltage	V <sub>ID</sub>	5.0	Vdc
Operating Temperature Range	TA	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C
Junction Temperature	TJ	+150	°C

### **ORDERING INFORMATION**

Device	Operating Temperature Range	Package
MC1490P	$T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	Plastic

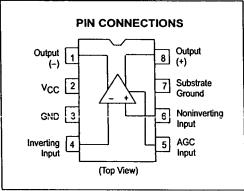


# WIDEBAND AMPLIFIER WITH AGC

SEMICONDUCTOR TECHNICAL DATA



P SUFFIX PLASTIC PACKAGE CASE 626



SCATTERING PARAMETERS ( $V_{CC}$ = +12 Vdc, $T_A$ = +25°C, $Z_0$ = 50 $\Omega$ )					
		f = N Ty			
Parameter	Symbol	30	60	Unit	
Input Reflection Coefficient	S <sub>11</sub>     011	0.95 -7.3	0.93 16	_ deg	
Output Reflection Coefficient	S <sub>22</sub>   #22	0.99 -3.0	0.98 -5.5	- deg	
Forward Transmission Coefficient	S <sub>21</sub>   021	16.8 128	14.7 64.3	- deg	
Reverse Transmission Coefficient	S <sub>12</sub> 012	0.00048 84.9	0.00092 79.2	_ deg	

ELECTRICAL CHARACTERISTICS (V<sub>CC</sub> = 12 Vdc, f = 60 MHz, BW = 1.0 MHz, T<sub>A</sub> = 25°C)

Characteristic	Figure	Symbol	Min	Тур	Max	Unit
Power Supply Current Drain	_	lcc	_	-	17	mA
AGC Range (AGC) 5.0 V Min to 7.0 V Max	19	MAGC	-60	-	-	dB
Output Stage Current (Sum of Pins 1 and 8)	_	Ю	4.0	-	7.5	mA
Single–Ended Power Gain R <sub>S</sub> = R <sub>L</sub> = 50 $\Omega$	19	Gp	40	-	-	dB
Noise Figure R <sub>S</sub> = 50 Ohms	19	NF	_	6.0	-	dB
Power Dissipation	_	PD	-	168	204	mW

Figure 1. Unneutralized Power Gain versus Frequency (Tuned Amplifier, See Figure 19)

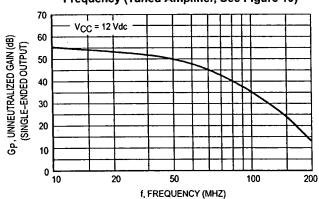


Figure 2. Voltage Gain versus Frequency (Video Amplifier, See Figure 20)

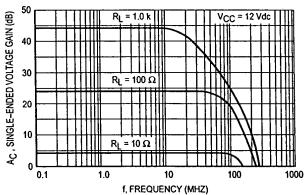


Figure 3. Dynamic Range: Output Voltage versus Input Voltage (Video Amplifier, See Figure 20)

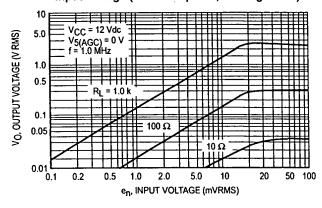


Figure 4. Voltage Gain versus Frequency (Video Amplifier, See Figure 20)

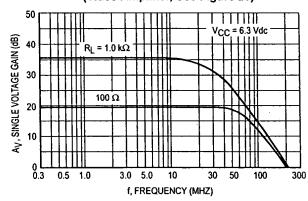


Figure 5. Voltage Gain and Supply Current versus Supply Voltage (Video Amplifier, See Figure 20)

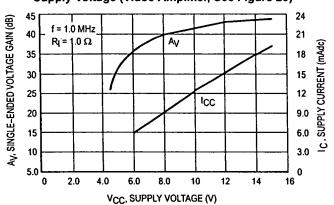


Figure 6. Typical Gain Reduction versus AGC Voltage

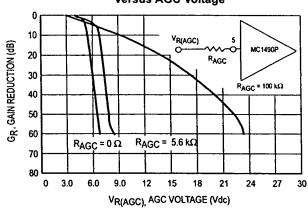


Figure 7. Typical Gain Reduction versus AGC Current

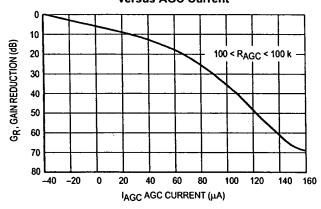


Figure 8. Fixed Tuned Power Gain Reduction versus Temperature (See Test Circuit, Figure 19)

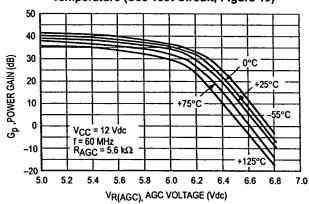


Figure 9. Power Gain versus Supply Voltage (See Test Circuit, Figure 19)

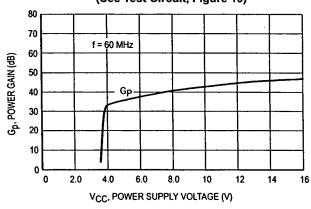


Figure 10. Noise Figure versus Frequency

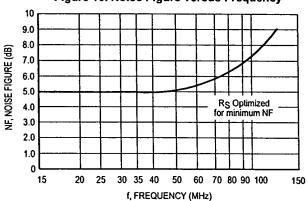


Figure 11. Noise Figure versus **Source Resistance** 20 18 V<sub>CC</sub> = 12 Vdc 16 NF, NOISE FIGURE (dB) 14 12 10 8.0 6.0 4.0 2.0 100 200 400 600 1.0 k 2.0 k 4.0 k 10 k RS, SOURCE RESISTANCE  $(\Omega)$ 

Figure 12. Noise Figure versus **AGC Gain Reduction** f = 30 MHz 35 BW = 1.0 MHz 30 NOISE FIGURE (dB) 25 20 Test circuit has tuned input providing a source resistance optimized for best noise figure. 10 0 -10 -40 -50 -60 -70 GR, GAIN REDUCTION (dB)

Figure 13. Harmonic Distortion versus AGC Gain Reduction for AM Carrier (For Test Circuit, See Figure 14)

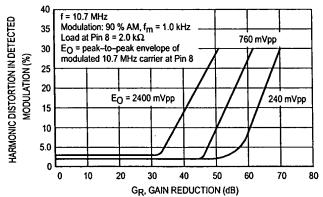
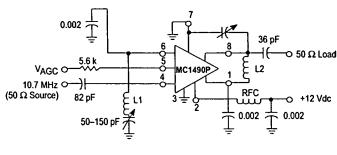


Figure 14. 10.7 MHz Amplifier Gain  $\approx$  55 dB, BW  $\approx$  100 kHz



L1 = 24 turns, #22 AWG wire on a T12–44 micro metal Toroid core (–124 pF) L2 = 20 turns, #22 AWG wire on a T12-44 micro metal Toroid core (-100 pF)

Figure 15. S<sub>11</sub> and S<sub>22</sub>, Input and Output Reflection Coefficient

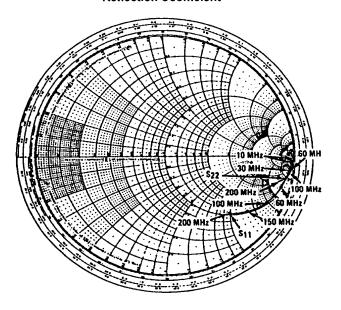


Figure 16. S<sub>11</sub> and S<sub>22</sub>, Input and Output Reflection Coefficient

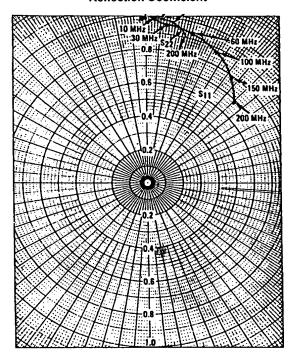


Figure 17. S<sub>21</sub>, Forward Transmission Coefficient (Gain)

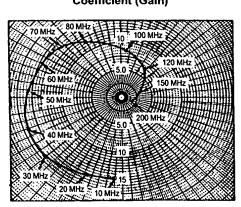


Figure 18. S<sub>12</sub>, Reverse Transmission Coefficient (Feedback)

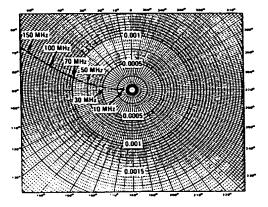
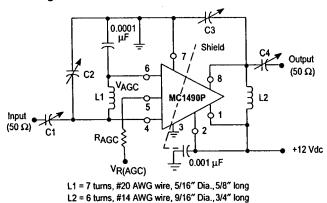


Figure 19. 60 MHz Power Gain Test Circuit



C1,C2,C3 = (1-30) pF C4 = (1-10) pF

# Figure 20. Video Amplifier

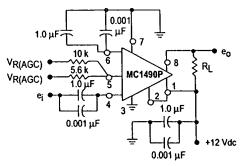
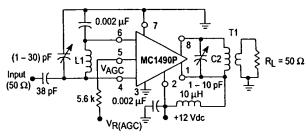
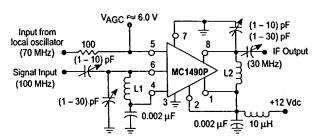


Figure 21. 30 MHz Amplifier (Power Gain = 50 dB, BW  $\approx$  1.0 MHz)



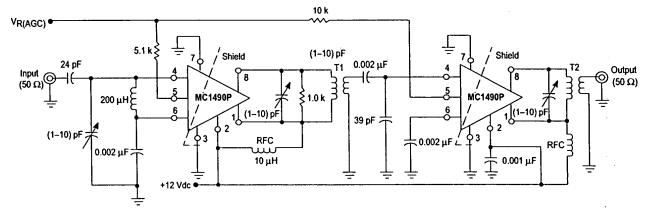
L1 = 12 turns, #22 AWG wire on a Toroid core, (T37–6 micro metal or equiv). T1: Primary = 17 turns, #20 AWG wire on a Toroid core, (T44–6). Secondary = 2 turns, #20 AWG wire.

Figure 22. 100 MHz Mixer



L1 = 5 turns, #16 AWG wire, 1/4", ID Dia., 5/8" tong L2 = 16 turns, #20 AWG wire on a Toroid core, (T44-6).

Figure 23. Two-Stage 60 MHz IF Amplifier (Power Gain ≈ 80 dB, BW ≈ 1.5 MHz)



T1: Primary Winding = 15 turns, #22 AWG wire, 1/4" ID Air Core Secondary Winding = 4 turns, #22 AWG wire, Coefficient of Coupling ≈ 1.0

T2: Primary Winding = 10 turns, #22 AWG wire, 1/4" ID Air Core Secondary Winding = 2 turns, #22 AWG wire, Coefficient of Coupling ≈ 1.0

# **DESCRIPTION OF SPEECH COMPRESSOR**

The amplifier drives the base of a PNP transistor operating common–emitter with a voltage gain of approximately 20. The control R1 varies the quiescent Q point of this transistor so that varying amounts of signal exceed the level  $V_\Gamma$ . Diode D1 rectifies the positive peaks of Q1's output only when these peaks are greater than  $V_\Gamma \simeq 7.0$  V. The resulting output is filtered by  $C_X$ ,  $R_X$ .

 $R_{X}$  controls the charging time constant or attack time.  $C_{X}$  is involved in both charge and discharge. R2 (the 150  $k\Omega$  and input resistance of the emitter–follower Q2) controls the decay time. Making the decay long and attack short is accomplished by making  $R_{X}$  small and R2 large. (A Darlington emitter–follower may be needed if extremely slow decay times are required.)

The emitter-follower Q2 drives the AGC Pin 5 of the MC1490P and reduces the gain. R3 controls the slope of signal compression.

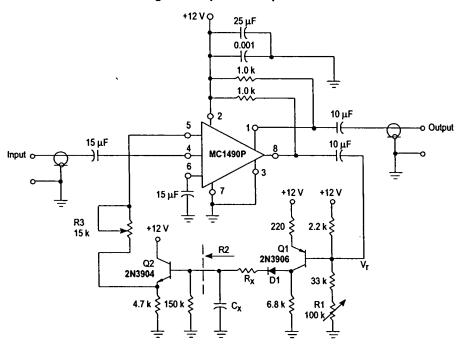
Table 1. Distortion versus Frequency

Frequency	Distortion		Distortion		
	10 mV e <sub>i</sub>	100 mV e <sub>i</sub>	10 mV e <sub>i</sub>	100 mV e <sub>i</sub>	
100 Hz	3.5%	12%	15%	27%	
300 Hz	2%	10%	6%	20%	
1.0 kHz	1.5%	8%	3%	9%	
10 kHz	1.5%	8%	1%	3%	
100 kHz	1.5%	8%	1%	3%	
	Notes 1 and 2		Notes	3 and 4	

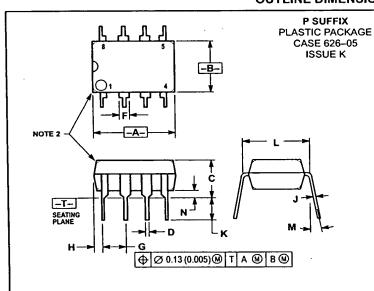
Notes:

- (1) Decay = 300 ms Attack = 20 ms
- (2)  $C_X = 7.5 \mu F$  $R_X = 0 \text{ (Short)}$
- (3) Decay = 20 ms Attack = 3.0 ms
- (4)  $C_X = 0.68 \mu F$  $R_X = 1.5 k\Omega$

Figure 24. Speech Compressor



### **OUTLINE DIMENSIONS**



- NOTES:
  1. DIMENSION L TO CENTER OF LEAD WHEN
- 1. DIMENSION L'IO CENTER OF LEAD WHEN FORMED PARALLEL.
  2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
  3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
В	6.10	6.60	0.240	0.260
U	3.94	4.45	0.155	0,175
۵	0.38	0.51	0.015	0.020
F	1,02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
-	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	_	10°		10°
N	0.76	1.01	0.030	0.040

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